

ZXTDC3M832TA

ZXTDC3M832TA Information

Part Number Manufacture Category Description Package	er Diodes Incorporated Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays TRANS NPN/PNP 50V/40V 4A/3A 8MLP 8-VDFN Exposed Pad For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



ZXTDC3M832TA Specifications

Manufastanan Dart Number		
Manufacturer Part Number	ZXTDC3M832TA	
Manufacturer	Diodes Incorporated	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Arrays	
Package	8-VDFN Exposed Pad	
Series	-	
Transistor Type	NPN, PNP	
Current - Collector (Ic) (Max)	4A, 3A	
Voltage - Collector Emitter Breakdown (Max)	50V, 40V	
Vce Saturation (Max) @ Ib, Ic	320mV @ 200mA, 4A / 370mV @ 250mA, 2.5A	
Current - Collector Cutoff (Max)	25nA	
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 2A, 2V / 60 @ 1.5A, 2V	
Power - Max	1W	
Frequency - Transition	165MHz, 190MHz	
Operating Temperature	-55°C ~ 150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	8-VDFN Exposed Pad	
Supplier Device Package	8-MLP (3x2)	
	Report errors?	

ZXTDC3M832TA Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

ZXTDC3M832TA Payment Methods





If you have any question about ZXTDC3M832TA, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com